





High Isolation Gate Drive Transformers



-  Rugged design for Industrial Applications
-  UL recognized, TUV approved to IEC 60950
-  Up to 4250Vrms gate to drive isolation
-  IEC 61558, IEC 61010 & IEC 60601 reinforced insulation compliant designs

Electrical Specifications @ 25°C - Operating Temperature -40°C to +125°C

Part Number ^{4,5}	Turns Ratio	ET (V * μsec MAX)	Primary Inductance (1-10) (μH MIN)	Leakage Inductance Gate to Drive (μH MAX)	DCR Drive (1-10) (mΩ ±20%)	DCR Gates (mΩ ±20%)	Hi-Pot	
							Drive-Gate (Vrms)	Gate-Gate (Vrms)
P0584NL	1:1:1	95	450	0.5	80	72	3000	1500
P0585NL	1:1:1:1	95	450	3.0	330	180	3000	1500*
P0584ANL	1:1:1	115	686	0.8	710	710	4250	1500
P0585ANL	1:1:1:1	115	686	4.6	710	710	4250	1500*

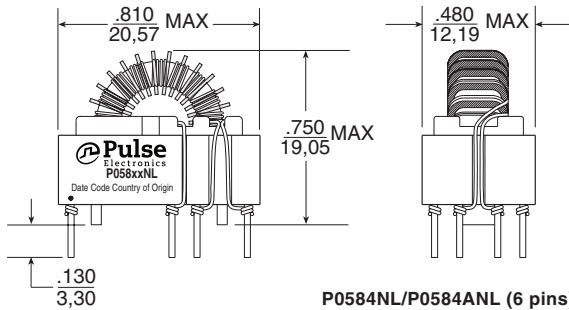
- Notes:**
1. These gate drive transformers are meant to operate between 50 and 300 kHz with a 12V, 45% bipolar waveform.
 2. The peak flux density should remain below 2100 Gauss to ensure that the core does not saturate. Use the following procedure to calculate the peak flux density:
 - A. Calculate the Volt-μsec product (ET):
 $ET = 10 * (\text{Drive Voltage}) * (\text{Don}) / (\text{Frequency in kHz})$
 - B. Calculate the operating flux density (B): $B_{PK} (\text{Gauss}) = X * ET / Ff$ where:
 Ff = 1 for unipolar drive applications and 2 for bipolar drive applications,
 X = 40 for -NL, 33 for -ANL
 3. The temperature rise of the component is calculated based on the total core loss and copper loss:
 - A. To calculate total copper loss (W), use the following formula:
 $\text{Copper Loss (W)} = I_{rms}^2 * (\text{DCR_Drive} + (\# \text{ of Gates}) * \text{DCR_Gates})$
 - B. To calculate total core loss (W), use the following formula:
 $\text{Copper Loss (W)} = 7.5E-5 * (\text{Frequency in kHz})^{1.67} * (X * ET/1000)^{2.532}$
 X = 20 for -NL, 16 for -ANL
 - C. To calculate temperature rise, use the following formula:
 $\text{Temperature Rise (C)} = 60.18 * (\text{Core Loss(W)} + \text{Copper Loss (W)})^{.833}$
 4. 500Vrms Hi-Pot between pins 5 & 6
 5. NL versions, which use triple insulated Teflon wire on the drive winding and magnetic wire on the gate windings, are TUV certified.
 ANL versions, which use triple insulated wire on both the drive and gate windings, are compliant with IEC 61558, IEC 61010 & IEC 60601.

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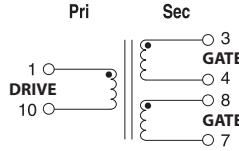
Mechanicals

Schematics

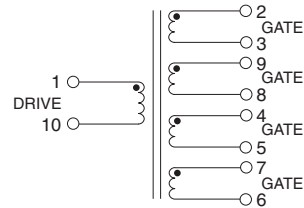
P058xxNL



P0584NL/P0584ANL

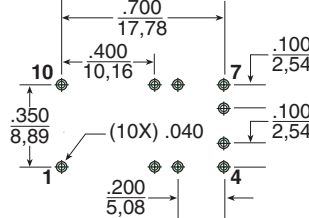
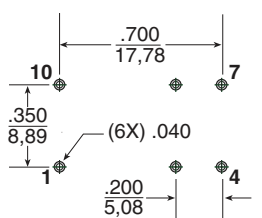
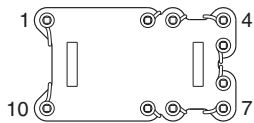


P0585NL/P0585ANL



P0584NL/P0584ANL (6 pins)

P0585NL/P0585ANL (10 pins)



SUGGESTED PCB HOLE PATTERN

Weight5 grams
Tray80/tray

Dimension: $\frac{\text{Inches}}{\text{mm}}$
Unless otherwise specified, all tolerances are $\pm \frac{.010}{0,25}$

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